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Supporting Information for

Base-Stabilized Silaimine and its Donor-Free Dimer Derived from the Reaction

of NHC-Supported Silylene with SiCl₄

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Experimental Section

General considerations: All operations were carried out under an atmosphere of dry argon or nitrogen by using modified Schlenck line and glovebox techniques. All solvents were freshly distilled from Na and degassed immediately prior to use. Elemental analyses were carried out on an Elemental Vario EL analyzer. The ¹H, ¹³C and ²⁹Si NMR spectroscopic data were recorded on Bruker Mercury Plus 300, 400 and 600 MHz NMR spectrometers. Infrared spectra were recorded on a Bio-Rad FTS 6000 spectrometer. The UV-vis spectra were recorded on a Shimadzu UV-2450 spectrometer and Emission spectra on an Edinburgh Analytical Instruments FL900CD spectrometer. ArN(SiMe₃)Si(I*i*Pr)Cl (1)¹ (Ar = 2,6-*i*Pr₂C₆H₃, I*i*Pr = 1,3-diisopropyl-4,5-dimethylimidazol-2-ylidene) was synthesized according to published procedure.

Synthesis of ArN=SiCl₂(IiPr) (2): A solution of SiCl₄ (1.5 ml, 0.53 mmol, 0.35 M solution in Et₂O) was added to a stirred solution of **1** (0.26g, 0.5 mmol) in Et₂O (5mL) at room temperature. Soon white suspension formed. The mixture was allowed to stir for 2h. After filtration, the residue white power is neat **2** (0.05g, 21.2%). M.p. 198-200 °C; ¹H NMR (400 MHz, C_6D_6): δ 0.95 (d, *J* = 7.0 Hz, 12H, CH(*CH*₃)₂), 1.34 (s, 6H, =CC*H*₃), 1.56 (d, *J* = 6.8 Hz, 12H, CH(*CH*₃)₂), 4.13 (m, 2H, Ar-*CH*(CH₃)₂), 6.62 (m, 2H, N-*CH*(CH₃)₂), 7.09 (m, 1H, Ar-*H*), 7.39 (d, 2H, Ar-*H*) ppm; ¹³C NMR (100.61 MHz, d⁸-THF): δ 10.69 (=CCH₃), 21.08 (CH(*C*H₃)₂), 24.16 (CH(*C*H₃)₂), 28.47 (Ar-*C*H(CH₃)₂), 51.73 (N-*C*H(CH₃)₂), 116.06, 122.01, 129.73, 139.90, 145.78 (Ar-*C*), 145.99 (N*C*N) ppm; ²⁹Si NMR (79.49 MHz, d⁸-THF): δ -107.03 ppm; Elemental analysis (%) calcd for C₂₃H₃₇Cl₂N₃Si: C, 60.77; H, 8.20; N, 9.24; Found: C, 60.26; H, 8.53; N, 8.93; IR (cm⁻¹): v 469.71, 541.48, 638.24, 757.49, 809.22, 915.63, 1038.81, 1104.74, 1171.35, 1209.04, 1244, 1312.82, 1373.38, 1622.99, 1963.51, 2274.55, 2324.13, 2976.06.

Synthesis of ArN(SiMe₃)SiCl₃ (3): A solution of SiCl₄ (1.5 ml, 1.36 mmol) in hexane (15 mL) was added to a stirred suspension of **1** (0.49 g, 1 mmol) in hexane (70 mL) at room temperature. Soon the suspension became clarified. The mixture was allowed to stir for overnight whereupon a white precipitate formed. After filtration (the residual solid was $IiPr \cdot SiCl_4$) and removal of solvents under vacuum afforded colorless solid **3** (0.35 g, 91.4%). M.p. 127°C-130°C; ¹H NMR (400 MHz, C₆D₆): δ 7.07 – 6.94 (m, 3H, Ar-*H*), 3.45 (m, 2H, C*H*(CH₃)₂), 1.25 (d, *J* = 6.8 Hz, 6H, CH(CH₃)₂), 1.16 (d, *J* = 6.8 Hz, 6H, CH(CH₃)₂), 0.19 (s, 9H, Si(CH₃)₃). ¹³C NMR (100.61 MHz, C₆D₆): δ 147.3, 138.5, 127.2, 124.8 (Ar-C), 28.5 (CH(CH₃)₂), 25.4 and 24.7 (CH(*C*H₃)₂), 1.7 (Si(*C*H₃)₃). ²⁹Si NMR (79.49 MHz, C₆D₆): δ -27.3 (*Si*Cl₃) ppm. Elemental analysis (%) calcd for C₁₅H₂₆Cl₃NSi₂: C, 47.05; H, 6.84; N, 3.66; Found: C, 47.01; H, 6.86; N, 3.61.

Path b for I*i*Pr·SiCl₄: Neat SiCl₄ (0.2 ml, 1.8 mmol) was added to a stirred solution of I*i*Pr (0.09g, 0.5 mmol) in toluene (10 mL) at ambient temperature. The mixture was allowed to stir for 1h, and then the volatiles were removed under vacuum. The residue was washed with n-hexane (5 ml) to afforded white powder I*i*Pr·SiCl₄ (0.14g, 80.0%). : ¹H NMR (400 MHz, C₆D₆): δ 6.00 (s, 2H, CH(CH₃)₂), 1.33 (s, 6H, =CCH₃), 1.13 (d, *J* = 7.0 Hz, 12H, CH(CH₃)₂). ¹³C NMR (100.61 MHz, C₆D₆): δ 154.59 (NCN), 125.64 (CH₃C=), 52.19 (CH(CH₃)₂), 20.76 (CH(CH₃)₂), 10.19 (=CCH₃). ²⁹Si NMR (79.49 MHz, C₆D₆): δ -104.95 (*Si*Cl₄) ppm.

Synthesis of ArN(SiMe₃)SiCl₂SiCl₃ (4') and (ArNSiCl₂)₂ (4): A suspension of 1 (0.25g, 0.5 mmol) in hexane (15mL) was added to a stirred solution of SiCl₄ (1.5 ml, 0.53 mmol, 0.35 M solution in Et₂O) in hexane (15 mL) at room temperature. The mixture was stirred overnight. After filtration (the residue white power was I/Pr·SiCl₄) and removal solvents, the remaining residue (a mixture of 4' (about 70%), 3, and undefined coproducts) was dissolved in toluene (15 ml) and heated at 80 °C for 16 h. Concentration to ca. 1~2 mL and storage at -10 °C afforded colorless crystals of 4 (0.09 g, 64.3%). 4': ¹H NMR (400 MHz, C₆D₆): δ 7.05 – 6.93 (m, 3H, Ar-*H*), 3.46 (m, 2H, C*H*(CH₃)₂), 1.25 (d, 6H, CH(C*H*₃)₂), 1.16 (d, 6H, CH(C*H*₃)₂), 0.18 (s, 9H, Si(C*H*₃)₃) ppm. ¹³C NMR (100.61 MHz, C₆D₆): δ 147.28, 138.54, 124.77, 28.49, 25.46, 24.63, 1.74 ppm. 4: Sublimation at 260 °C; ¹H NMR (400 MHz, C₆D₆): δ 7.06-7.12 (m, 6H, Ar-*H*), 3.86 (m, 4H, C*H*(CH₃)₂), 1.29 (d, *J* = 6.8 Hz, 24H, CH(C*H*₃)₂) ppm; ¹³C NMR (100.61 MHz, C₆D₆): δ 147.44, 129.43, 127.50 and 125.09 (Ar-*C*), 28.64 (*C*H(CH₃)₂), 25.66 (CH(*C*H₃)₂) ppm; ²⁹Si NMR (79.49 MHz, d⁸-THF): δ - 43.15 (*Si*Cl₂) ppm; Elemental analysis (%) calcd for C₂₄H₃₄Cl₄N₂Si₂: C, 52.55; H, 6.25; N, 5.11; Found: C, 52.37; H, 6.03; N, 5.56;

X-ray Structural Determinations. All intensities for compounds **2** and **4** were collected with a Rigaku Saturn 724 CCD diffractometer using graphite-monochromated Mo K $_{\alpha}$ radiation ($\lambda = 0.71073$ Å) at 113(2) K. The structure was solved by direct methods (*SHELXS-97*)² and refined by full-matrix least squares on F^2 . All non-hydrogen atoms were refined anisotropically and hydrogen atoms by a riding model (*SHELXL-97*).³ Crystals of **2** suitable for X-ray analysis were grown from mixture of THF and toluene. And crystals of **4** suitable for X-ray analysis were grown from toluene. Crystallographic data for **2** and **4** are given in Table S1.

Compound	2	4
CCDC No.	1418863	1418862
Empirical formula	$C_{23}H_{37}Cl_2N_3Si \cdot C_7H_8$	$C_{24}H_{34}Cl_4N_2Si_2$
Formula weight	546.68	548.51
Temperature/K	113(2)	113(2)
Wavelength /Å	0.71073	0.71073
Crystal system	Monoclinic	Monoclinic
space group	P2(1)/n	P2(1)/n
a/Å	9.490(4)	9.730(6)
b/Å	14.842(6)	11.344(7)
c/Å	21.882(9)	13.051(8)
α (°)	90	90
β (°)	91.321(7)	96.115(9)
γ (°)	90	90
V/ Å ³	3081(2)	1432.3(15)
Ζ	4	2
$d_{calcd.}$ (g/cm ³)	1.179	1.272
F(000)	1176.0	576
Limiting indices	-11≤h≤10	-8≤h≤12,
	-17≤k≤17	-14≤k≤14
	-26≤l≤26	-17 <u>≤</u> 1 <u>≤</u> 16
Reflections collected / unique	23056 / 5427	12871 / 3411
GOF	1.073	0.923
$R_{I} (I > 2\sigma(I))$	0.0656	0.0343
$wR(F^2) (I > 2\sigma(I))$	0.1669	0.0791
R_I (all data)	0.0825	0.0476
$wR(F^2)$ (all data)	0.1781	0.0818

Table S1: Crystallographic data for **2** and **4**.

References

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